

***High-Energy Phonon Confinement in
Nanoscale Metal Multilayers
Observed by Nuclear Resonant Inelastic X-Ray
Scattering (NRIXS)***

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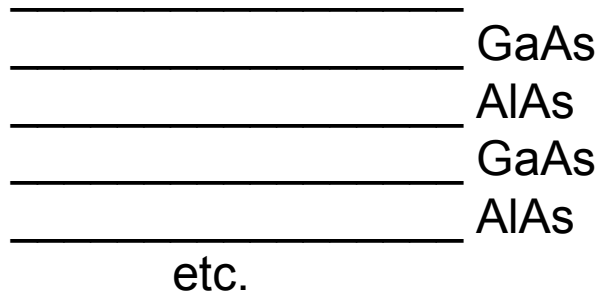
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Semiconductor superlattices:



e.g., [GaAs/AlAs] superlattices

confinement of optical phonons (at $k = 0$)
observed by Raman spectroscopy.
However: **no vibrational DOS !**

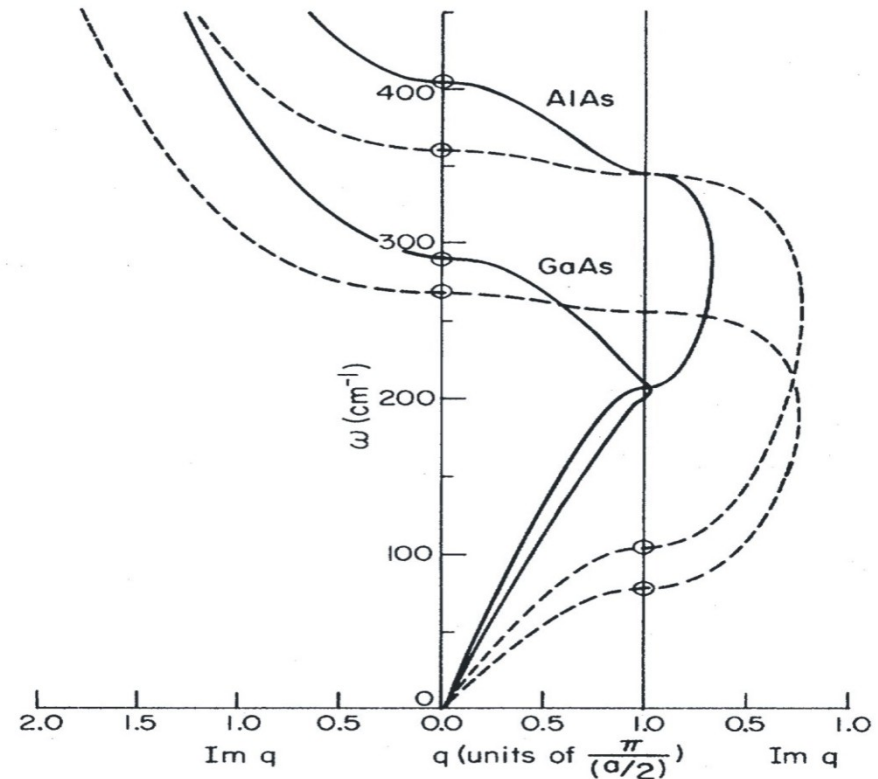
Metal superlattices/multilayers:

Raman spectroscopy not applicable,
only NRIXS provides vibrational DOS !

Important question:

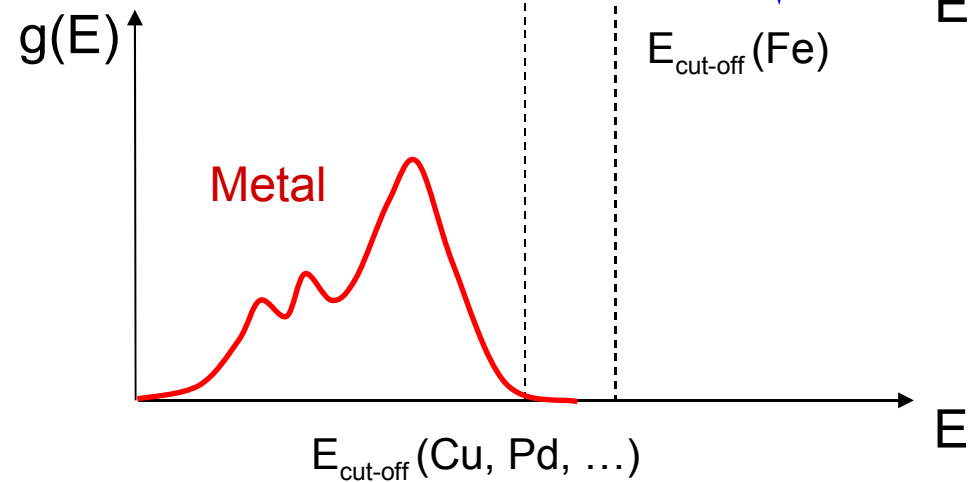
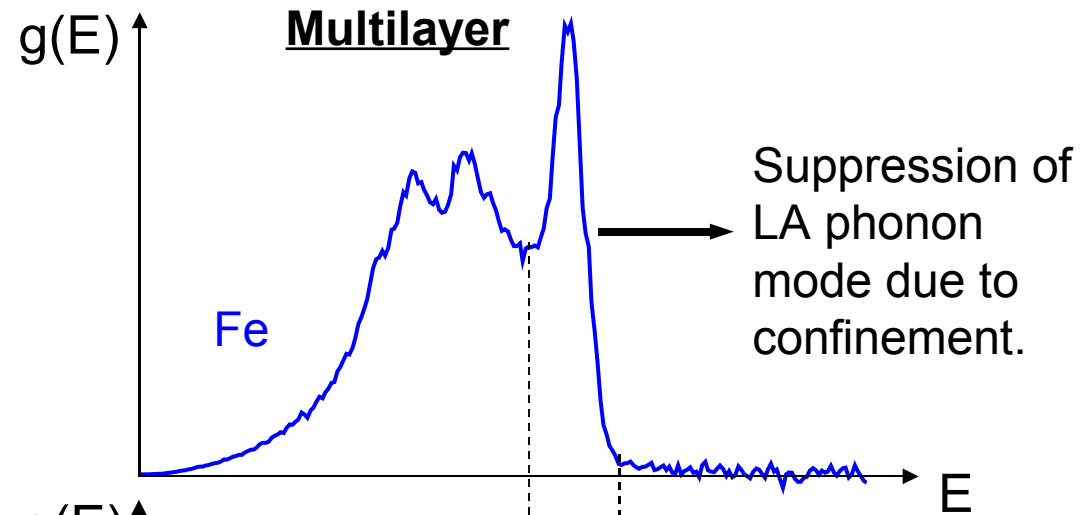
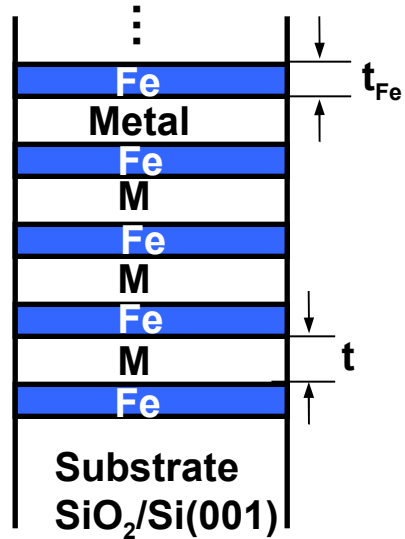
Does the vibrational (phonon) DOS change in
nanoscale multilayers ?

C. Colvard et al.,
PRB 31 (1985) 2080





MBE growth



LA-Phonon confinement in multilayers is a result of:

- Limited film thickness.
- Energy mismatch of $g(E)$ of the two materials.

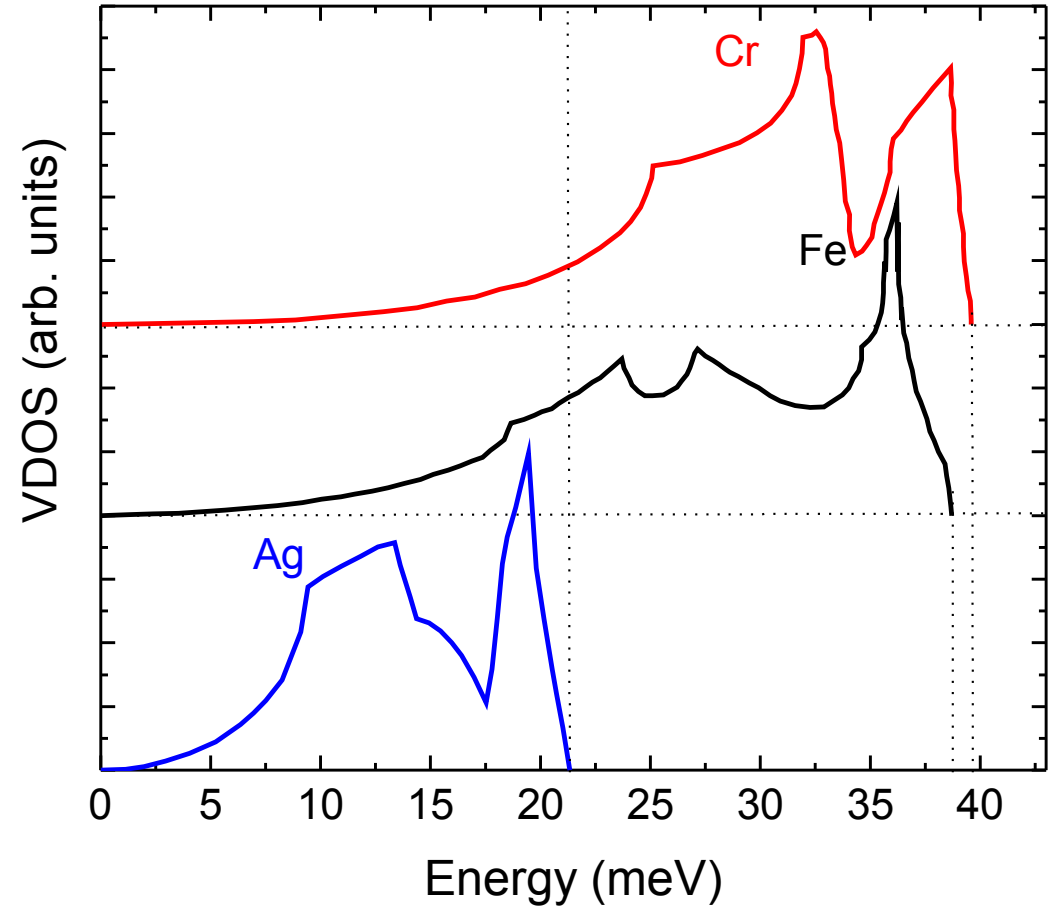


Material (M)	LA – Phonon Cut-off frequency (THz)
MgO ??	12
Al	10
Cr	9.5
Fe	9.4
Co	8.0
Cu	7.2
Pd	6.8
Ru	6.2
	(7.7) optical
Ag	5.0
In	3.4

No confinement

Confinement

Energy mismatch

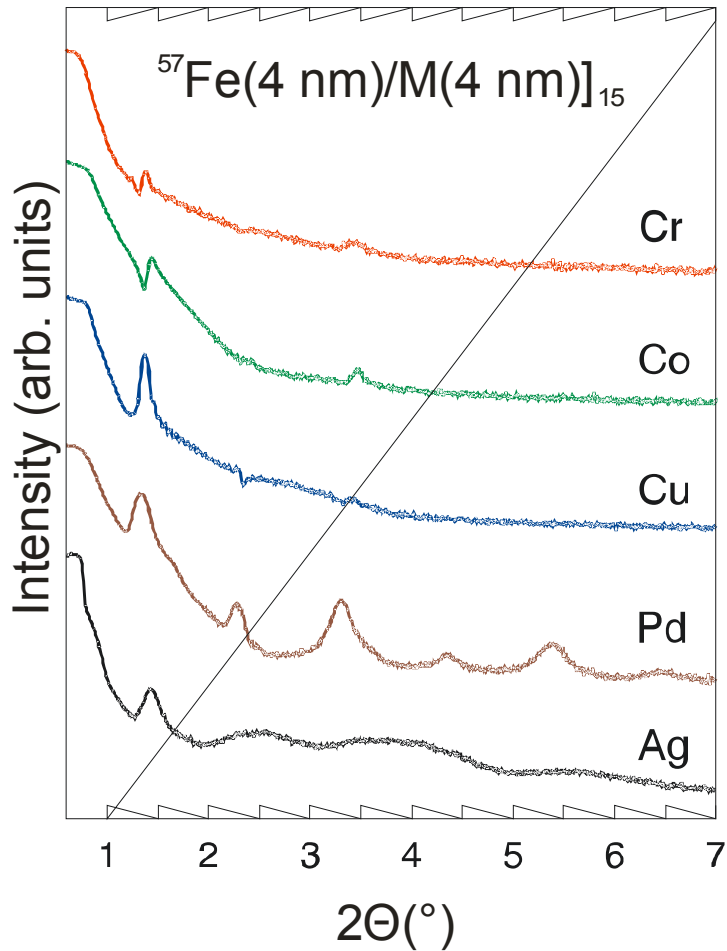


1 THz = 4.13550 meV

Sample Preparation and Characterization

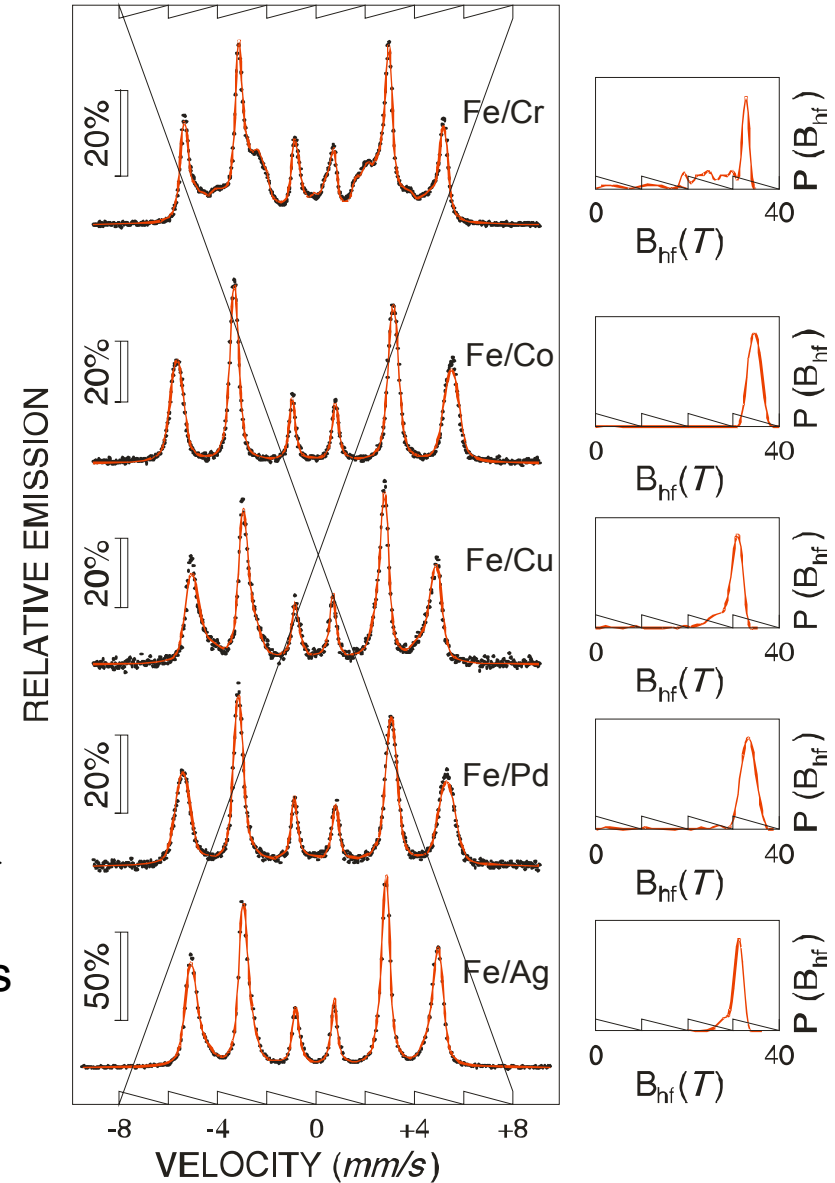


- Substrate: SiO₂/Si(001)
- Deposition: Molecular Beam Epitaxy (MBE) at RT
- Polycrystalline films (XRD): bcc-Fe(110)

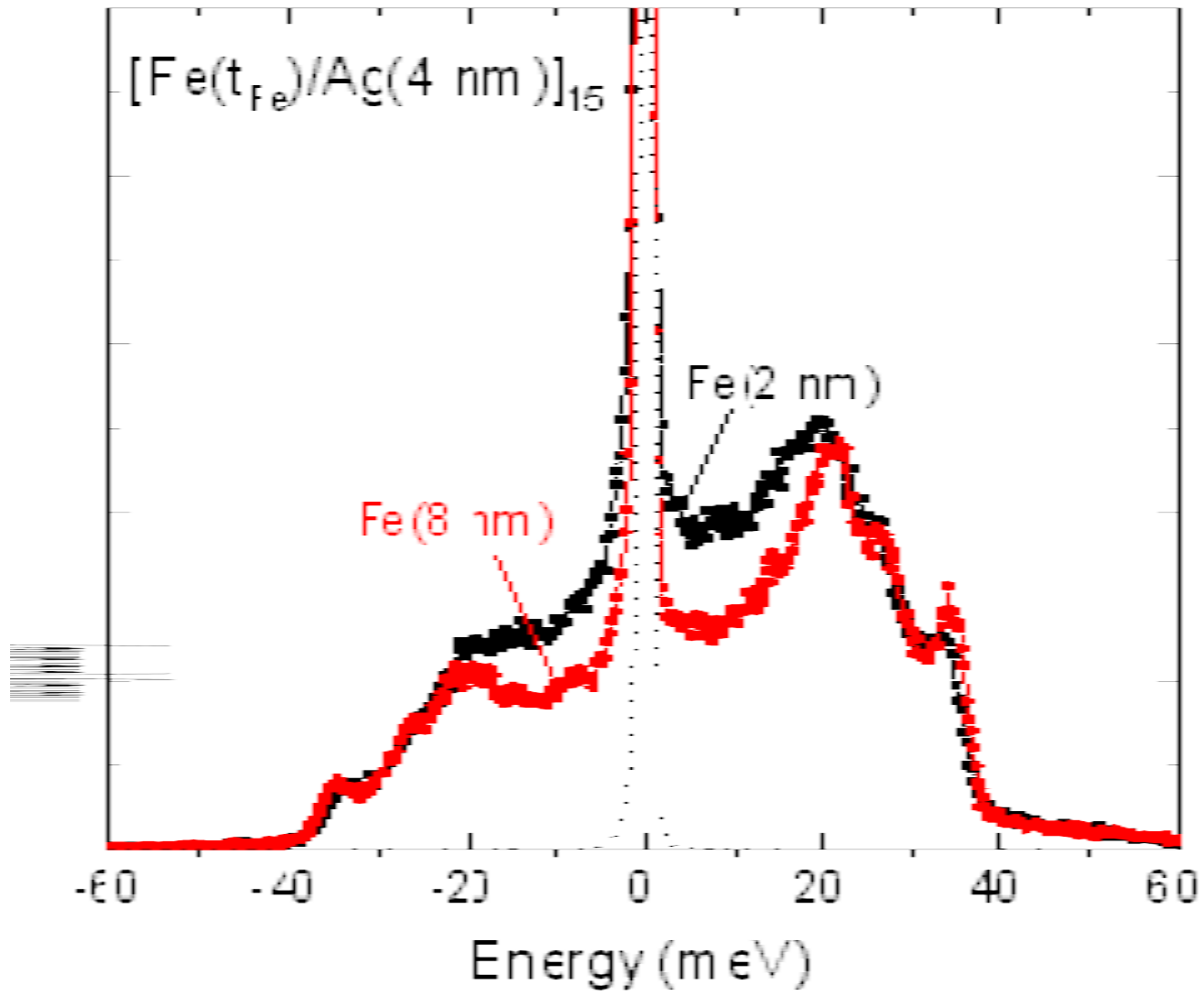


X-ray Reflectometry

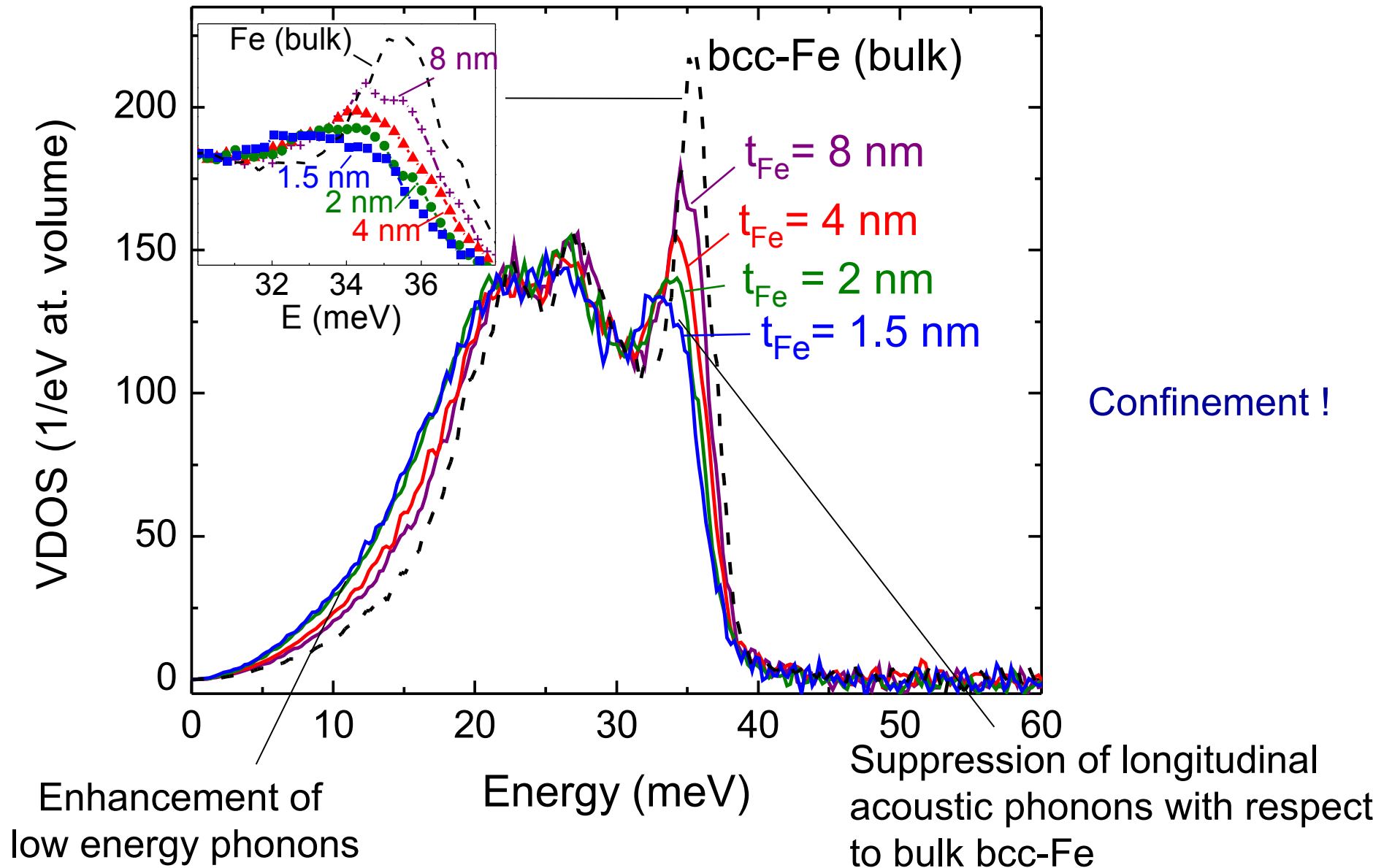
Only 1-2 ML →
intermixing at
Fe/M interfaces

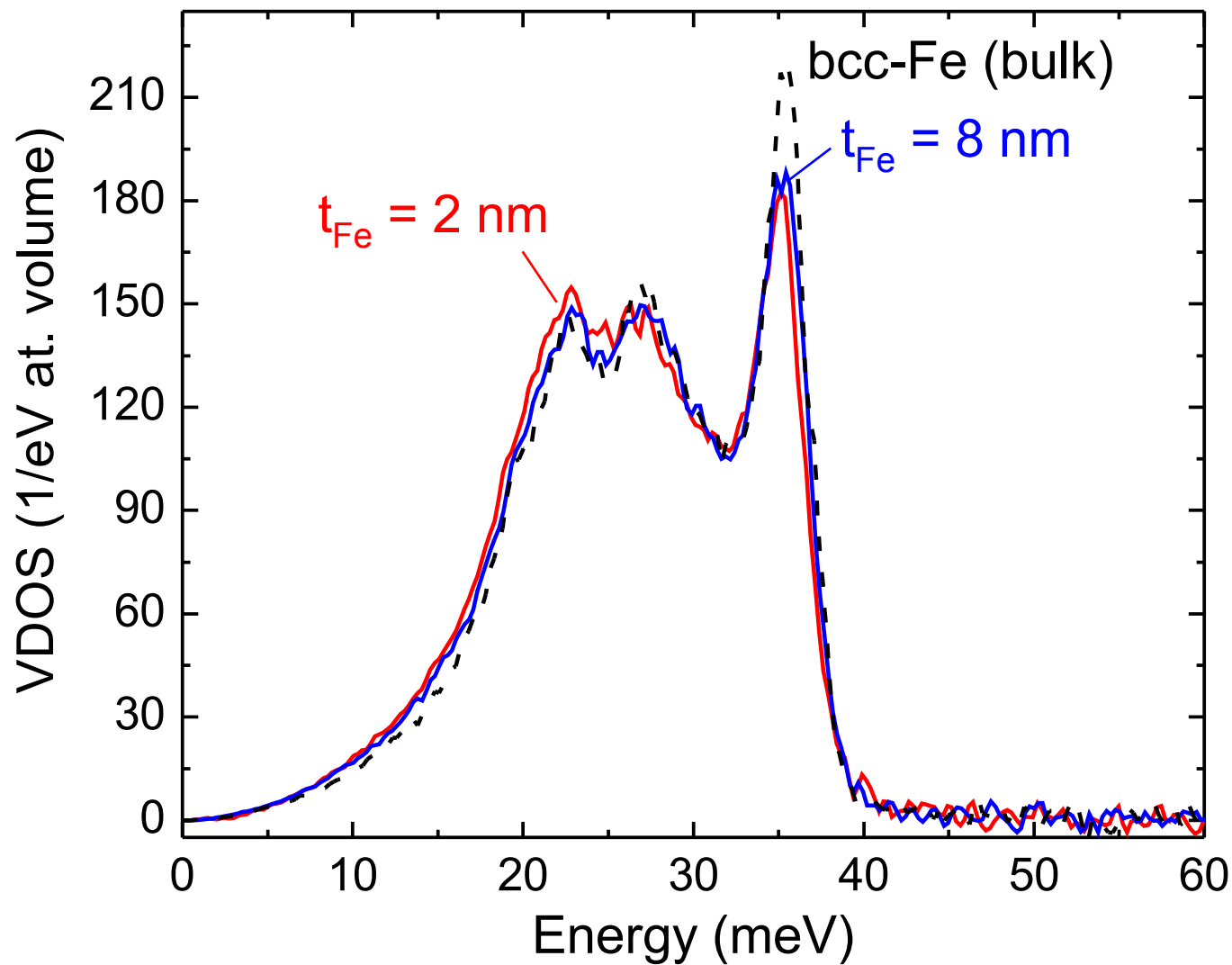


⁵⁷Fe CEMS: [⁵⁷Fe(1.5nm)/M(4nm)]₁₅



Size-effects!



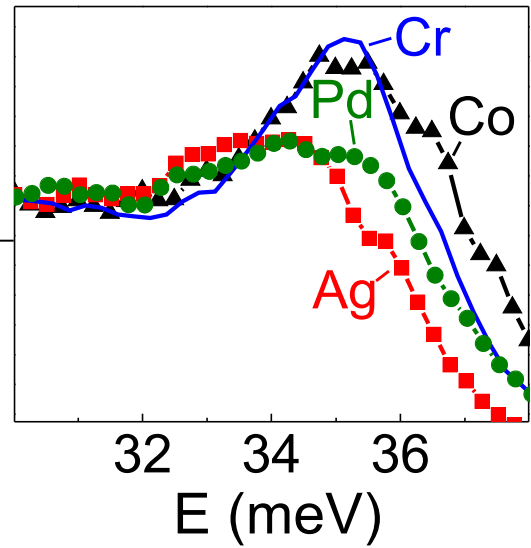
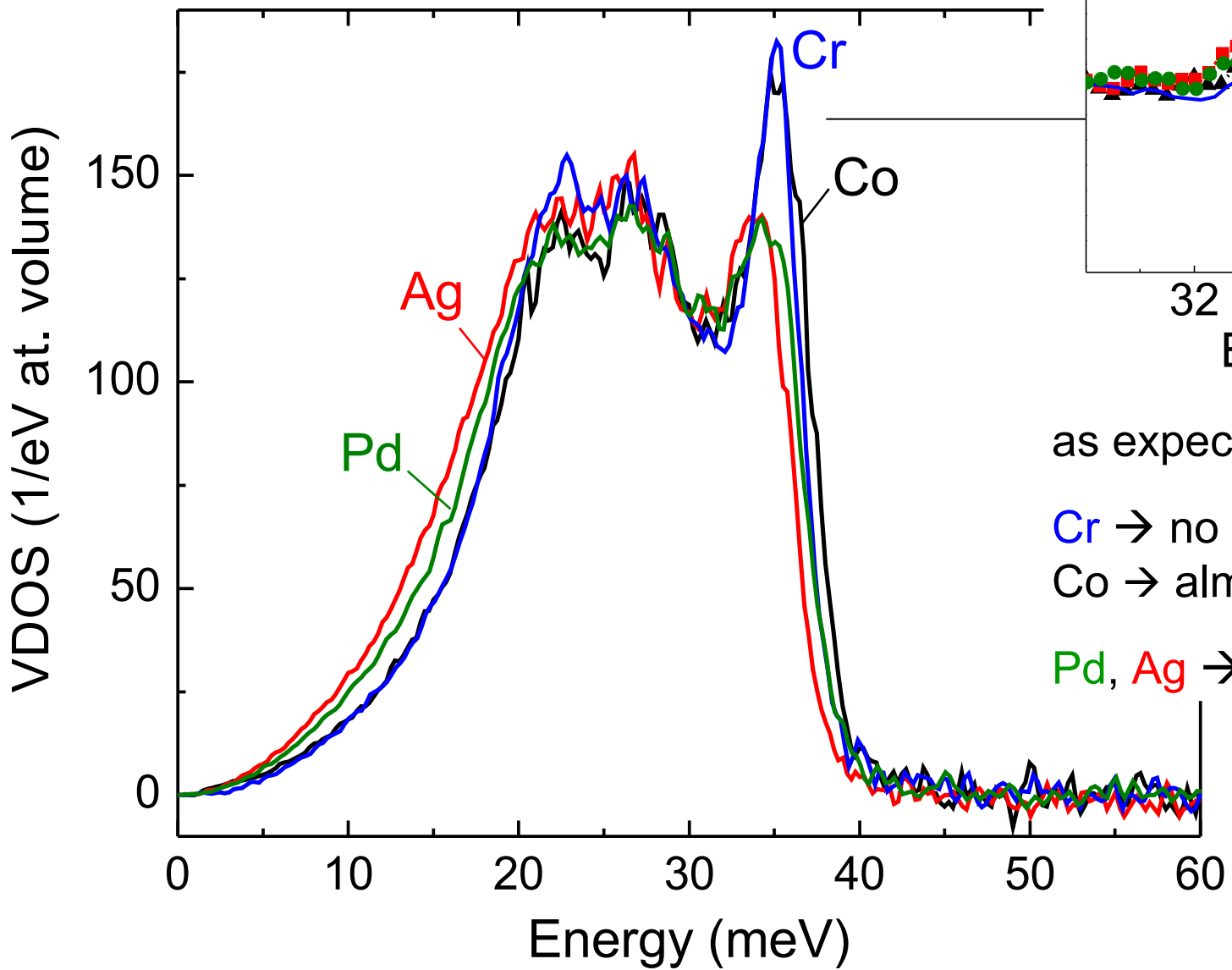


Lack of Confinement !



Dependence on metal M: $[^{57}\text{Fe}(2\text{ nm})/\text{Metal}(4\text{ nm})]_{15}$ Multilayers

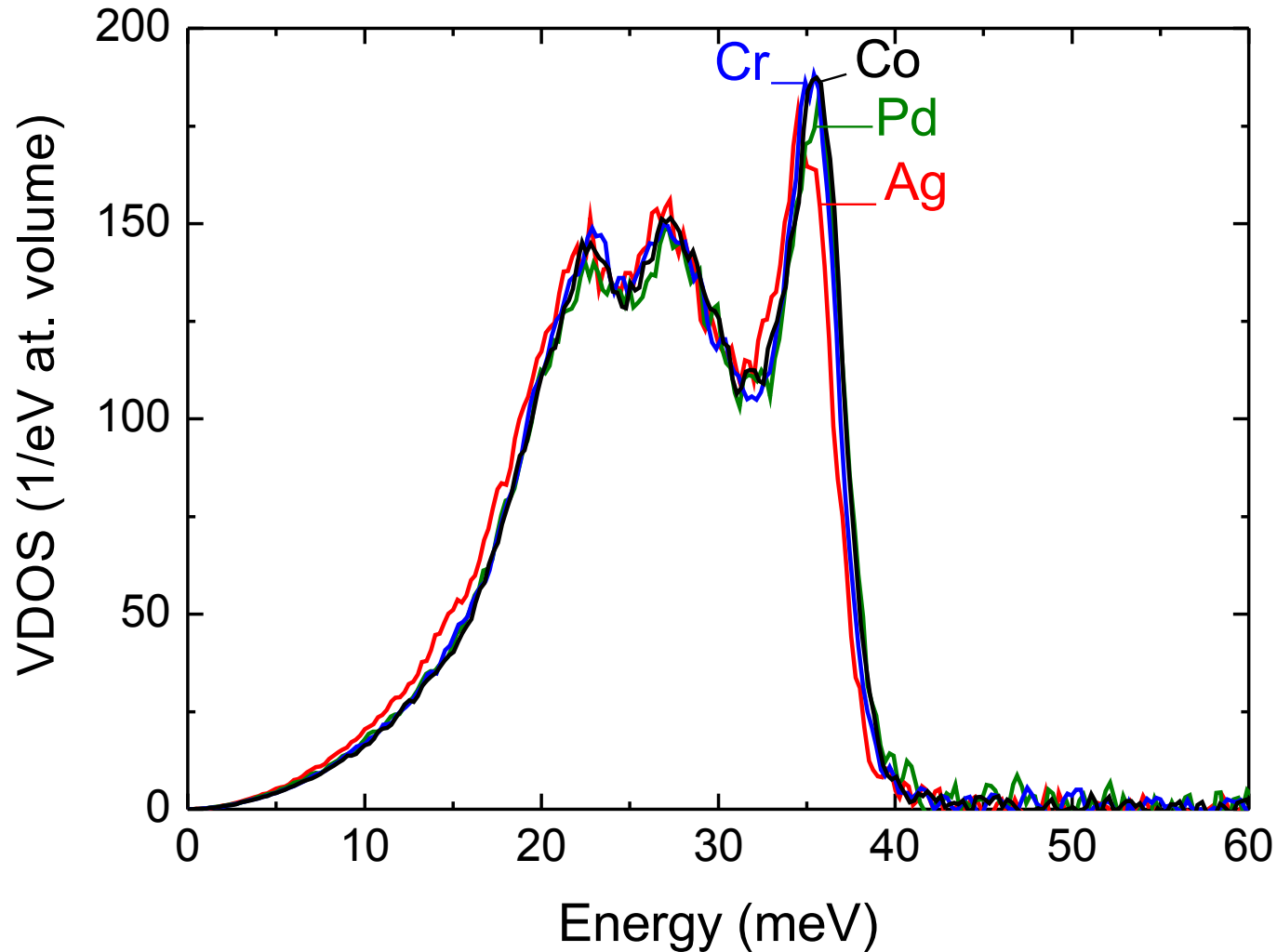
$t_{\text{Fe}} = 2\text{ nm}$, $t_{\text{M}} = 4\text{ nm}$



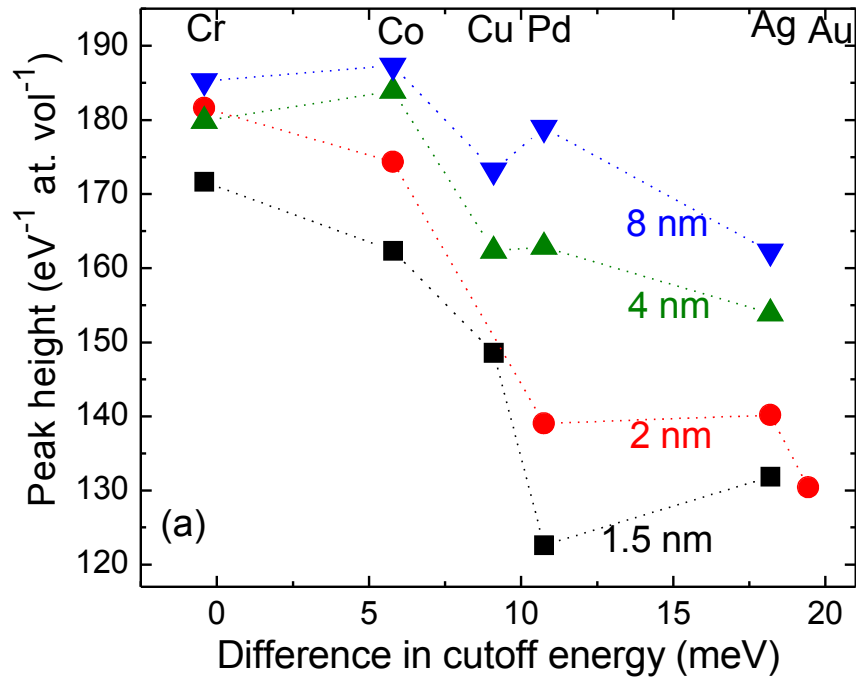
as expected:
Cr \rightarrow no confinement
Co \rightarrow almost no confinement
Pd, Ag \rightarrow confinement



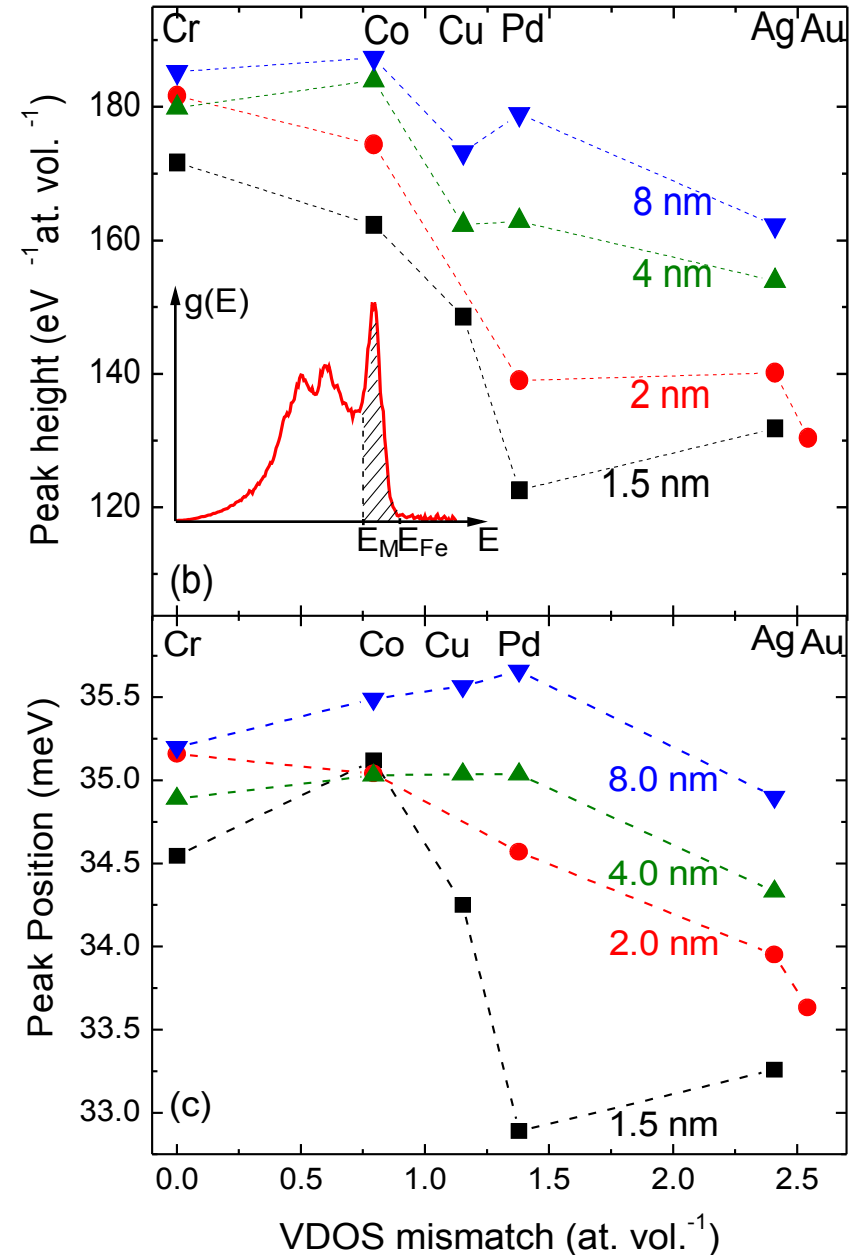
Negligible or weak phonon confinement for $t_{\text{Fe}} = 8\text{ nm}$



LA-Phonon Peak Height / Peak Position vs. VDOS Mismatch



- Thickness dependent phonon confinement: Cu, Pd, Ag, Au.





Phonon Spectrum in $[^{57}\text{Fe}(t_{\text{Fe}}/\text{M}(4\text{nm}))_{15}]$ Multilayers by NRIXS:

- (1) $t_{\text{Fe}} < 4 \text{ nm}$: -Thickness dependent **suppression** and **shift** of the LA phonon peak near 36 meV for $\text{M} = \text{Ag}, \text{Pd}, \text{Cu}$ (“soft metals”)
→ **Phonon confinement** due to energy mismatch in $g(E)$
 - Lack of phonon confinement for Cr, Co (“hard metals”) due to energy matching
- (2) $t_{\text{Fe}} = 8 \text{ nm}$: - Negligible or weak confinement
- (3) ^{57}Fe probe layers:
 - **Interface effects** on the 36-meV LA-phonons **disappear a few MLs** (1-3 ML) **away** from the Fe/M interface

Roldan et al., PRB 77 (2008) 165410

Ruckert et al., Hyperfine Int. 126 (2000) 363



Open questions:

- Is the measured $g(E)$ a „layer projected“ VDOS ?
→ Angular-dependent NRIXS, e.g., with the beam close to the surface normal
- Why are the TA modes of Fe hardly affected by the layered structure ?